

CMOS Quad **True/Complement Buffer**

High Voltage Types (20-Volt Rating)

CD4041UB types are guad true/ complement buffers consisting of n- and p-channel units having low channel resistance. and high current (sourcing and sinking) capability. The CD4041UB is intended for use as a buffer, line driver, or CMOS-to-TTL driver, it can be used as an ultra-low power resistor-network driver for A/D and D/A conversion, as a transmission-line driver, and in other applications where high noise immunity and low power dissipation are primary design requirements.

The CD4041UB types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

MAXIMUM RATINGS, Absolute-Maximum Values:

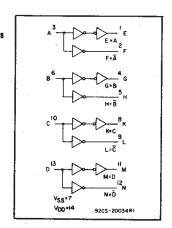
DC SUPPLY-VOLTAGE RANGE, (VDD)

Features:

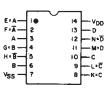
- Balanced sink and source current; approximately 4 times standard "B" drive
- Equalized delay to true and complement outputs
- 100% tested for quiescent current at 20 V Maximum input current of 1 μ A at 18 V over full package temperature range; 100 nA at 18 V and 25°C
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- High current source/sink driver
- CMOS-to-DTL/TTL Converter Buffer
- **Display driver**
- **MOS clock driver**
- **Resistor** network driver (Ladder or weighted R)
- Buffer
- **Transmission line driver**



CD4041UB Types



92CS-20755R1

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COMMERCIAL CMOS HIGH VOLTAGE IC8

TOP VIEW TERMINAL ASSIGNMENT

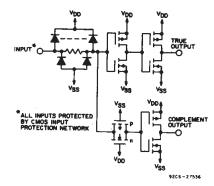
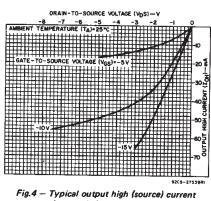


Fig.1 - Schematic diagram 1 of 4 buffers.

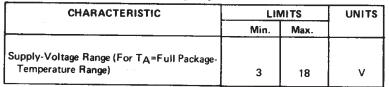


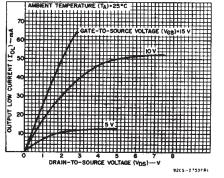
characteristics.

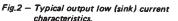
Voltages referenced to V _{SS} Terminal)0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS
DC INPUT CURRENT, ANY ONE INPUT ±10mA
POWER DISSIPATION PER PACKAGE (PD):
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$
For T _A = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)
OPERATING-TEMPERATURE RANGE (TA)55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max

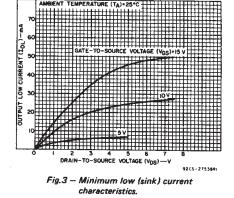
RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:





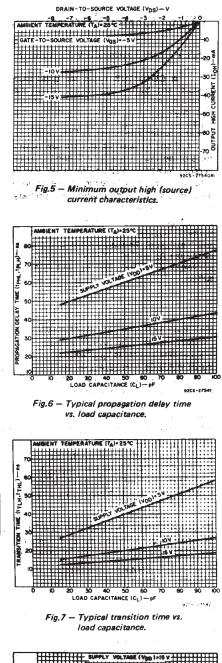


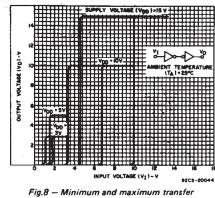


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STATIC ELECTRICAL CHARACTERISTICS

CHARAC-				LIMITS AT INDICATED TEMPERATURES (°C)										
TERISTIC		DITION		LIN	ITS AT	INDICA	TED TE	MPERA	UNITS					
	Vo	VIN	V _{DD}						+25					
	(V)	(V)	(V)	-55	40	+85	+125	Min.	Тур.	Max.				
Quiescent		0,5	5	1	1	30	30	<u> </u>	0.02	. 1				
Device		0,10	10	2	2	60	60	—	0.02	2	μA			
Current		0,15	15	4		120	120	· ·	0.02	4				
DD Max.	<u>`</u>	0,20	20	20	20	600	600	-	0.04	20				
Output Low														
(Sink)	0.4	0,5	5	2.1	1.8	1.3	1.2	1.6	3.2	· _				
Current,	0.5	0,10	10	6.25	5.6	4	3.5	5	10					
IOL Min.	1.5	0,15	15	24	23	15.5	13	19 .	38	(- .	mA			
Output High	4.6	0,5	5	-2.1	-1.8	-1.3	-1.2	-1.6	-3.2	-				
(Source)	2.5	0,5	5	-8.4	-6.7	-5.3	-4.6	-6.4	-12.8	_				
Current,	9.5	0,10	10	-6.25	-5.6	-4	-3.5	-5	_10					
IOH Min.	13.5	0,15	15	-24	-23	-15.5	-13	-19	-38]				
Output Volt-					•									
age:	—	0,5	5		0.0)5		-	0	0.05				
Low-Level,	-	0,10	10		0.0)5		-	0	0.05				
V _{OL} Max.	-	0,15	15		0.0)5		-	0	0.05				
Output Volt-														
age:		0,5	5		4.9	95		4.95	5	-				
High-Level,		0,10	10		9.9	95	1.1	9.95	10	-				
V _{OH} Min.	-	0,15	15		14.	95		14.95	15	-				
Input Low	0.5,4.5	— ·	5		-1				_	1				
Voltage, 📜	1,9	_	10		1	2		-	-	2]			
V _{IL} Max,	1.5,13.5		15		2.5				-	2.5	. v			
Input High	0.5,4.5	·	5		2	ļ		4	_	-]			
Voltage,	1,9	-	10		8	3		8		_	_			
V _{IH} Min.	1.5,13.5	-	15		12.	5		12.5	-	-				
Input		1. A.			14				E E	1				
Current,	+	0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	μΑ			
IIN Max.														



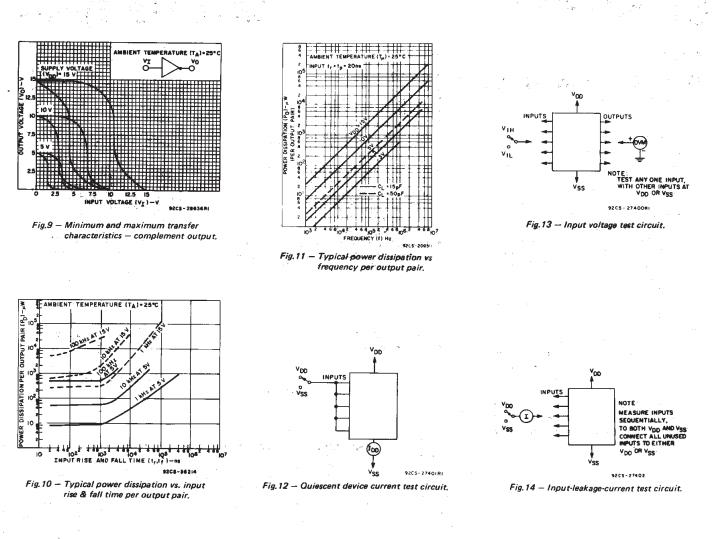


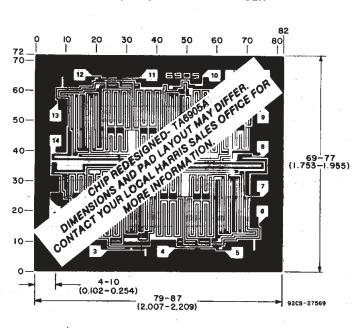
characteristics - true output.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r,t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω

	COND	ITIONS	LII			
CHARACTERIS		V _{DD} Volts	Тур.	Max.	UNITS	
Propagation Delay Tin		5	60	120	1	
	tPHL,		10	35	70	ns
· · · · ·	^t PLH		15	.25	50	
			5	40	80	
Transition Time	THL		10	20	40	ns
	TEH		15	15	30	· · ·
Input Capacitance	CIN	Any Input		15	22.5	pF







Dimensions and pad layout for the CD4041UBH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated Grid graduations are in mils (10^{-3} inch).

COMMERCIAL CMOS HIGH VOLTAGE ICs



4-Feb-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	(-)		•		•	(-)	(6)	(-)		()	
CD4041UBE	ACTIVE	PDIP	Ν	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4041UBE	Samples
CD4041UBF	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4041UBF	Samples
CD4041UBF3A	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4041UBF3A	Samples
CD4041UBM	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4041UBM	Samples
CD4041UBM96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4041UBM	Samples
CD4041UBMT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4041UBM	Samples
CD4041UBPW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM041UB	Samples
CD4041UBPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM041UB	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4041UB, CD4041UB-MIL :

- Catalog: CD4041UB
- Military: CD4041UB-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

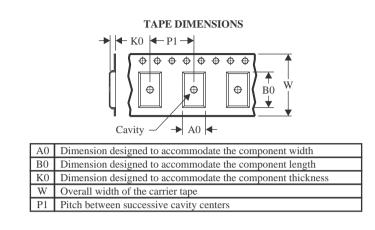


Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



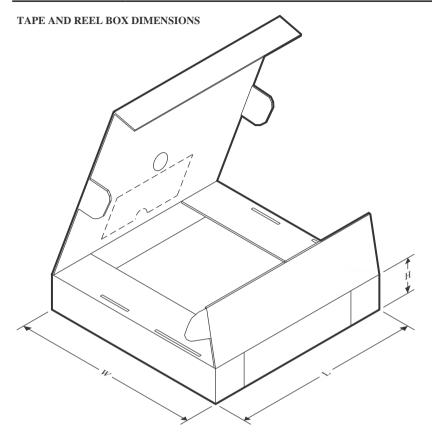
*All dimensions are nominal												
Device	•	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4041UBM96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4041UBMT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD4041UBPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

3-Jun-2022



*All dimensions are nominal

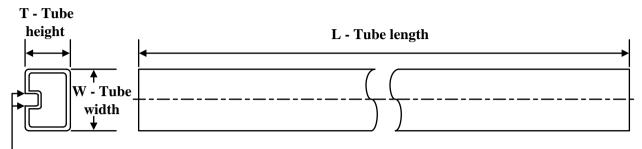
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4041UBM96	SOIC	D	14	2500	356.0	356.0	35.0
CD4041UBMT	SOIC	D	14	250	210.0	185.0	35.0
CD4041UBPWR	TSSOP	PW	14	2000	356.0	356.0	35.0

TEXAS INSTRUMENTS

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3-Jun-2022

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD4041UBE	N	PDIP	14	25	506	13.97	11230	4.32
CD4041UBE	N	PDIP	14	25	506	13.97	11230	4.32
CD4041UBM	D	SOIC	14	50	506.6	8	3940	4.32
CD4041UBPW	PW	TSSOP	14	90	530	10.2	3600	3.5

GENERIC PACKAGE VIEW

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



J0014A



PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.

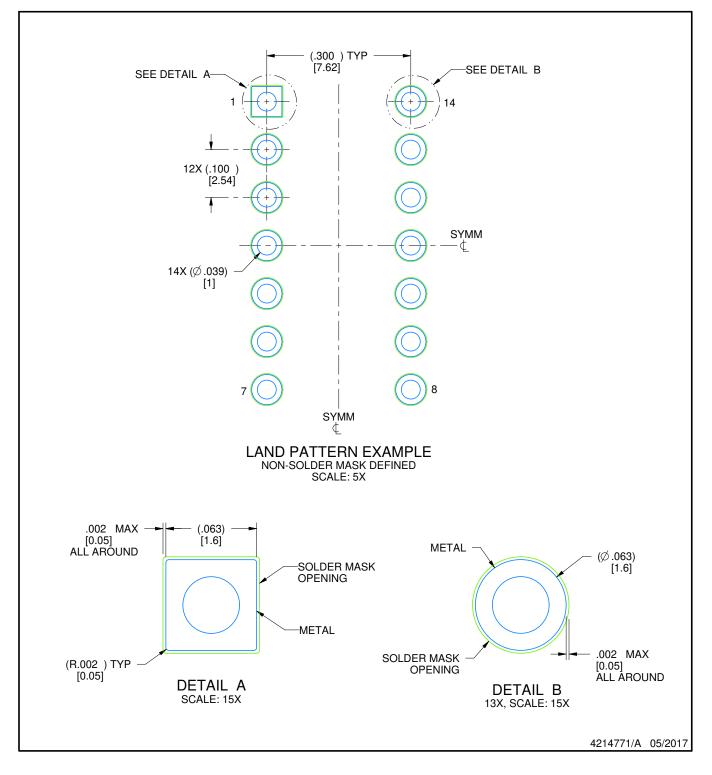


J0014A

EXAMPLE BOARD LAYOUT

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE





D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the international difference of the international difference

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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